



DMP6023LFGQ

60V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C		
2014	$25m\Omega @ V_{GS} = -10V$	-7.7A		
-60V	$33m\Omega @ V_{GS} = -4.5V$	-6.8A		

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AECQ101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: POWERDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 5)

Part Number	Case	Packaging
DMP6023LFGQ-7	POWERDI [®] 3333-8	2,000/Tape & Reel
DMP6023LFGQ-13	POWERDI [®] 3333-8	3,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

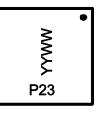
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



P23 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 13 = 2013) WW = Week Code (01 ~ 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-60	V		
Gate-Source Voltage		V _{GSS}	±20	V	
	Steady State	T _A = +25°C T _A = +70°C	ID	-7.7 -6.2	А
Continuous Drain Current (Note 7) $V_{GS} = -10V$	t<10s	T _A = +25°C T _A = +70°C	ID	-10.3 -8.2	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-55	А		
Maximum Continuous Body Diode Forward Current	Is	-2.2	А		
Avalanche Current, L = 0.1mH	I _{AS}	-35.5	А		
Avalanche Energy, L = 0.1mH	E _{AS}	62.9	mJ		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 6)		PD	1.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Р	123	°C/W
mermai Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ ext{ heta}JA}$	69	
Total Power Dissipation (Note 7)		PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	D	60	°C/W
merinal Resistance, Junction to Amblent (Note 7)	t<10s	$R_{ extsf{ heta}JA}$	34	
Thermal Resistance, Junction to Case (Note 7)	$R_{ ext{ heta}JC}$	6.3		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Cymbol	WIIII	- YP	Max	Onit		
Drain-Source Breakdown Voltage		-60			V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	BV _{DSS}	_	_	-1	μA	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	-1	_	-3	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		_	— 25 — 0	mΩ	$V_{GS} = -10V, I_D = -5A$		
Static Dian-Source On-Resistance	R _{DS(ON)}		_	33	11152	$V_{GS} = -4.5V, I_{D} = -4A$	
Diode Forward Voltage	V _{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)	•					·	
Input Capacitance	C _{iss}		2569	_	pF	N 20V/ V 0V/	
Output Capacitance	Coss		179	_	pF	− V _{DS} = -30V, V _{GS} = 0V, − f = 1MHz	
Reverse Transfer Capacitance	C _{rss}		143	_	pF		
Gate Resistance	Rg		8	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg		26.5	-	nC		
Total Gate Charge (V _{GS} = -10V)	Qg		53.1	_	nC		
Gate-Source Charge	Q _{gs}	_	7.1	_	nC	$V_{DS} = -30V, I_{D} = -5A$	
Gate-Drain Charge	Q _{gd}	_	12.6		nC	7	
Turn-On Delay Time	t _{D(ON)}	_	6	_	ns	V _{GS} = -10V, V _{DS} = -30V,	
Turn-On Rise Time	t _R	-	7.1	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	110	_	ns	$R_G = 3\Omega, I_D = -5A$	
Turn-Off Fall Time	tF	_	62		ns	1	
Body Diode Reverse Recovery Time	t _{RR}	_	20		ns	$L_{-} = 50 di/dt = 1000 / uc$	
Body Diode Reverse Recovery Charge	Q _{RR}	—	14		nC	— I _F = -5A, di/dt = 100A/μs	

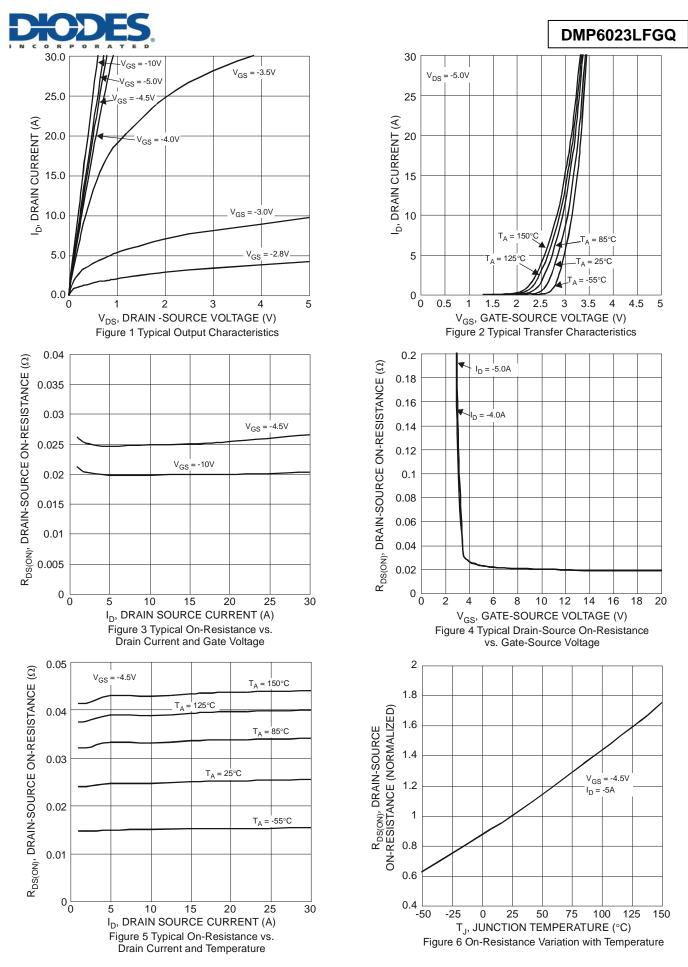
Notes: 6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

8. Short duration pulse test used to minimize self-heating effect.

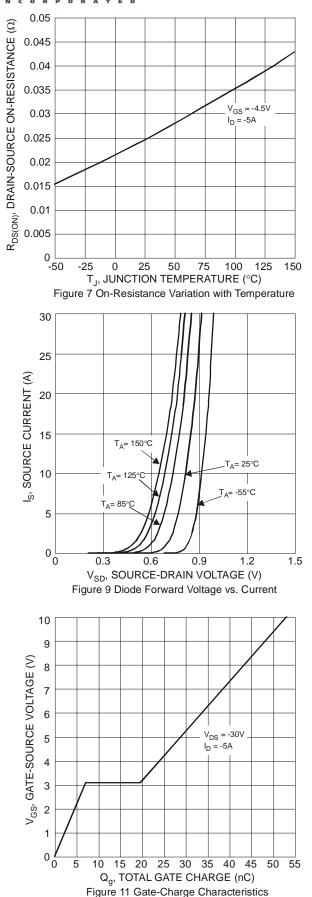
9. Guaranteed by design. Not subject to product testing.

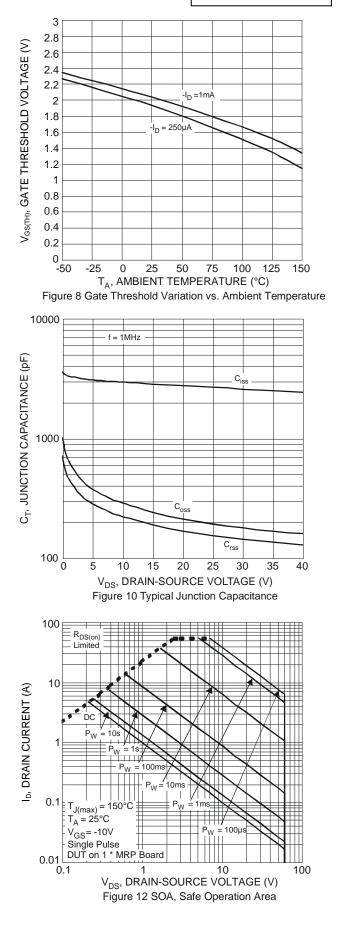
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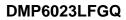




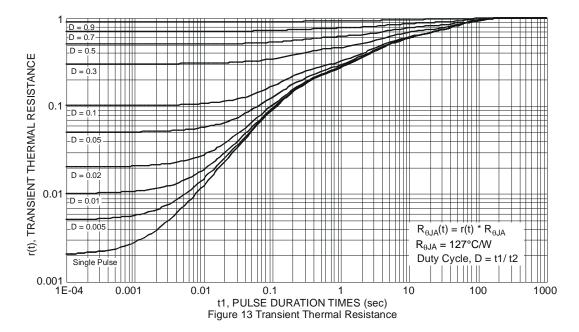
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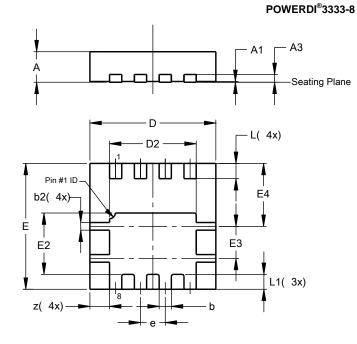






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

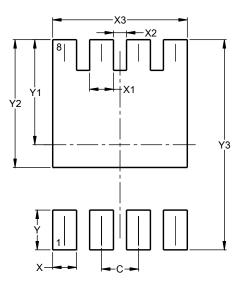


POWERDI [®] 3333-8						
Dim	Dim Min		Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
E	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	-	-	0.65			
L	0.35	0.45	0.40			
L1	_	-	0.39			
z	_	_	0.515			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

POWERDI[®]3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700



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